Demonstration Board EPC9107 Quick Start Guide

28 V Buck Converter featuring EPC2015



DESCRIPTION www.epc-co.com

The EPC9107 demonstration board is a 3.3 V output, 1 MHz buck converter with an 15 A maximum output current and 9 V to 28 V input voltage range. The demonstration board features the EPC2015 enhancement mode (*eGaN*®) field effect transistor (FET), as well as the Texas Instruments LM5113 gate driver.

The EPC9107 board contains the complete power stage (including eGaN FETs, driver, inductor and input/output caps) in a compact $\frac{1}{2}$ x $\frac{1}{2}$ alount to showcase the performance that can be achieved using the *eGaN* FETs and *eGaN* driver together.

The EPC9107 demonstration board is 3" square and contains a fully closed loop buck converter with optimized control loop.

There are also various probe points to facilitate simple waveform measurement and efficiency calculation. A complete block diagram of the circuit is given in Figure 1. For more information on the EPC2015 eGaN FETs or LM5113 driver, please refer to the datasheet available from EPC at www.epc-co.com and www.Tl.com. These datasheets, as well that of the LT3833 controller should be read in conjunction with this quick start guide.

Table 1: Performance :	Summary (TA = 25 °C)
------------------------	----------------------

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V _{IN}	Bus Input Voltage Range		9		28	٧
V _{out}	Switch Node Output Voltage			3.3		V
I _{OUT}	Switch Node Output Current				15*	Α
f _{sw}	Switching frequency			1000		kHz
	Peak Efficiency	12 V _{IN} , 10 A I _{OUT}		96.1		%
	Peak Efficiency	28 V _{IN} , 12 A I _{OUT}		93.5		%
	Full Load Efficiency	12 V _{IN} , 15 A I _{OUT}		95.6		%
	Full Load Efficiency	28 V _{IN} , 15 A I _{OUT}		93.3		%

^{*} Maximum limited by inductor saturation

Quick Start Procedure

Demonstration board EPC9107 is easy to set up to evaluate the performance of the EPC2015 *eGaN* FETs and LM5113 driver. Refer to Figure 2 for proper connect and measurement setup and follow the procedure below:

- 1. With power off, connect the input power supply bus between V_{IN} and GND banana jacks as shown.
- 2. With power off, connect the active (constant current) load as desired between V_{OLIT} and GND banana jacks as shown.
- 3. Turn on the supply voltage to the required value (more than 9V, but do not exceed the absolute maximum voltage of 28 V on V_{IN}).
- 4. Measure the output voltage to make sure the board is fully functional and operating no-load.
- 5. Turn on active load to the desired load current while staying below the maximum current (15 A)
- 6. Once operational, adjust the bus voltage and load current within the allowed operating range and observe the output switching behavior, efficiency and other parameters.
- 7. For shutdown, please follow steps in reverse.

NOTE. When measuring the high frequency content switch node of gate voltage, care must be taken to avoid long ground leads. Measure these by placing the oscilloscope probe tip on the top pad of D3 and grounding the probe directly across D3 on the bottom pad provided for switch node and using the right hand pad of R24 and the GND pad below it for gate voltage. See Figure 3 for proper scope probe technique. Measuring the switch node with a high bandwidth (\geq 500MHz) probe and high bandwidth scope (\geq 1GHz) is recommended.

NOTE. The dead-times for both the leading and trailing edges have been set for optimum full load efficiency. Adjustment is not recommended, but can be done at own risk by replacing R21 and R22 with potentiometers P1 and P2. This should be done while monitoring both the input current and switch-node voltage to determine the effect of these adjustments. Under no circumstance should the input pins to the LM5113 be probed during operation as the added probe capacitance will change the device timing.

CIRCUIT PERFORMANCE

The EPC9107 demonstration circuit was designed to showcase the size and performance that can readily be achieved at 1 MHz operation using eGaN FETs for supply voltages up to 28V or more. Since a closed loop controller is included on board, the associated losses must also be lumped into any efficiency measurement that is performed. In an effort to mitigate these losses and focus on the efficiency of the power stage, the controller is powered from the output through an unregulated charge pump supplied from the output. Thus the controller and gate drive losses are still included, but the associated conversion loss from the input supply is improved.

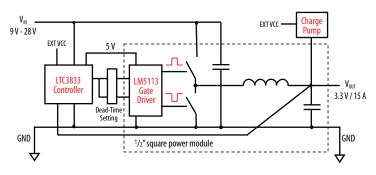


Figure 1: Block Diagram of EPC9107 Demonstration Board

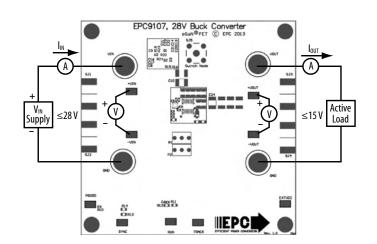


Figure 2: Proper Connection and Measurement Setup

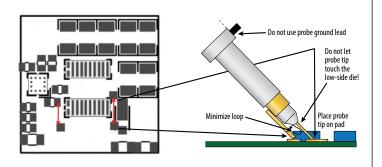


Figure 3: Proper Measurement of Switch Node or Gate Voltage

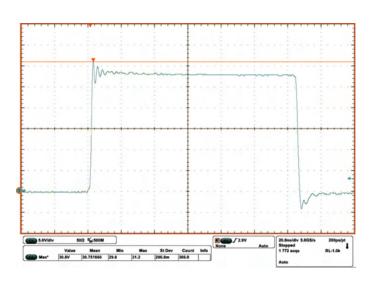


Figure 4: Typical waveforms for 28 V to 3.3 V / 15 A (1 MHz) CH1: Switch node voltage

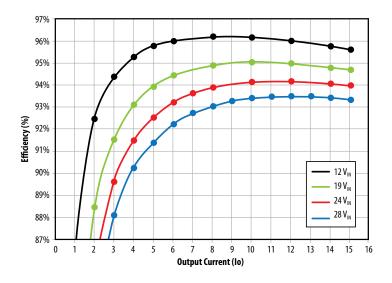
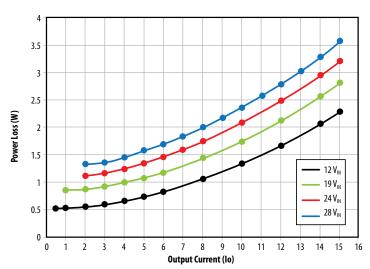


Figure 5: Typical efficiency and power loss curves for 12V, 19V, 24V and 28V input

THERMAL CONSIDERATIONS

The EPC9107 demonstration board thermal image for steady state full load operation is shown in Figure 6. The EPC9107 is intended for bench evaluation with low ambient temperature and convection cooling. The addition of heat-sinking and forced air cooling could increase the current capability of the demonstration circuit, but care must be taken to not exceed the absolute maximum die temperature of 125°C and stay within the constraints of the other components within the circuit, most notably the saturation of the output inductor.

NOTE. The EPC9107 demonstration board does not have any thermal protection on board.



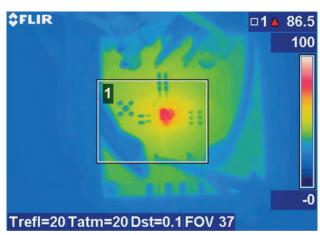
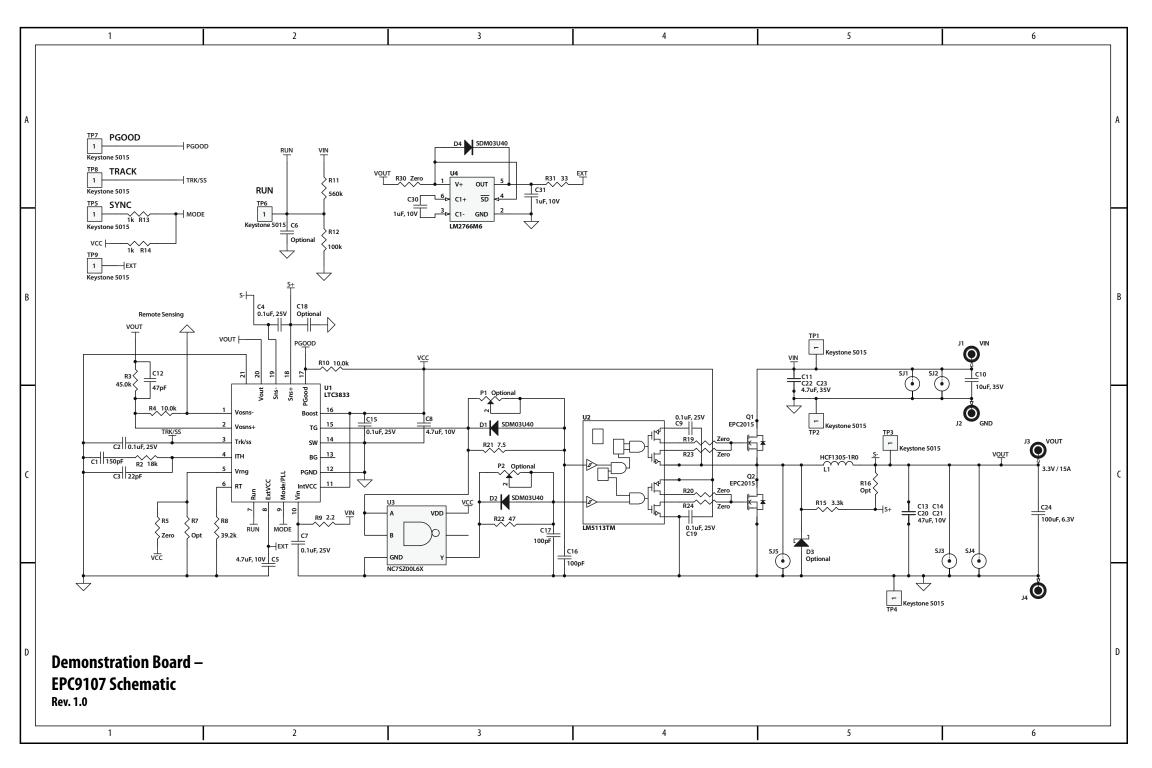


Figure 6: Thermal image of EPC9107 under full load condition: $28 \, V_{\text{NV}}$, $15 \, A_{\text{OUT}}$ with convection cooling

Table 2 : Bill of Material

1 1 C1 Capacitor, 150pF, 5%, 50V, NP0 Murata, GRM1885C1H12JA01D 2 1 C3 Capacitor, 22pF, 5%, 50V, NP0 Murata, GRM1885C1H1220JA01D 3 1 C12 Capacitor, 47pF, 5%, 50V, NP0 TDK, C1608C0G1H470J 4 6 C2, C4, C7, C9, C15, C19 Capacitor, 0.1uF, 10%, 25V, X5R TDK, C1005XSR1E104K 5 2 C5, C8 Capacitor, 4.7uF, 10%, 10V, X5R TDK, C1608XSR1A475K 6 1 C10 Capacitor, 4.7uF, 10%, 35V, X5R Taiyo Yuden, GMK325BJ106KN 7 2 C11, C22, C23 Capacitor, 4.7uF, 10%, 35V, X5R TDK, C2012XSR1A476M 8 4 C13, C14, C20, C21 Capacitor, 4.7uF, 10%, 35V, X5R TDK, C2012XSR1A476M 9 2 C16, C17 Capacitor, 100pF, 5%, 50V, NP0 Kemet, C0402C101K5GACTU 10 1 C24 Capacitor, 100uF, 20%, 6.3V, X5R TDK, C2012XSR1A105K0508B 11 2 C30, C31 Capacitor, 100uF, 20%, 6.3V, X5R TDK, C1005XSR1A105K0508B 12 2 D1, D2, D4 Schottky Diode, 30V Diodes Inc., SDM03U40-7 </th <th></th>	
2 1 C3 Capacitor, 22pF, 5%, 50V, NPO Murata, GRM1885C1H220JA01D 3 1 C12 Capacitor, 47pF, 5%, 50V, NPO TDK, C1608C0G1H470J 4 6 C2, C4, C7, C9, C15, C19 Capacitor, 0.1uF, 10%, 25V, X5R TDK, C100SXSR1E104K 5 2 C5, C8 Capacitor, 4.7uF, 10%, 10V, X5R TDK, C1608XSR1A475K 6 1 C10 Capacitor, 10uF, 20%, 35V, X5R Taiyo Yuden, GMK325BJ106KN 7 2 C11, C22, C23 Capacitor, 4.7uF, 10%, 35V, X7R TDK, C2012XSR1A476M 8 4 C13, C14, C20, C21 Capacitor, 47uF, 20%, 10V, X5R TDK, C2012XSR1A476M 9 2 C16, C17 Capacitor, 100pF, 5%, 50V, NPO Kemet, C0402C101K5GACTU 10 1 C24 Capacitor, 100pF, 20%, 6.3V, X5R Kemet, C1206C107M9PACTU 11 2 C30, C31 Capacitor, 100uF, 20%, 10V, X5R TDK, C1005X5R1A105K050BB 12 2 D1, D2, D4 Schottky Diode, 30V Diodes Inc., SDM03U40-7 13 4 J1, J2, J3, J4 Banana Jack Keystone, 575-4 <tr< td=""><td></td></tr<>	
3 1 C12 Capacitor, 47pF, 5%, 50V, NPO TDK, C1608C0G1H470J 4 6 C2, C4, C7, C9, C15, C19 Capacitor, 0.1uF, 10%, 25V, X5R TDK, C100SX5R1E104K 5 2 C5, C8 Capacitor, 4.7uF, 10%, 10V, X5R TDK, C1608XSR1A475K 6 1 C10 Capacitor, 10uF, 20%, 35V, X5R Taiyo Yuden, GMK325BJ106KN 7 2 C11, C22, C23 Capacitor, 4.7uF, 10%, 35V, X7R TDK, C2012X6S1V475K125AB 8 4 C13, C14, C20, C21 Capacitor, 4.7uF, 20%, 10V, X5R TDK, C2012X5R1A476M 9 2 C16, C17 Capacitor, 100pF, 5%, 50V, NP0 Kemet, C0402C101K5GACTU 10 1 C24 Capacitor, 100uF, 20%, 6.3V, X5R Kemet, C1206C107M9PACTU 11 2 C30, C31 Capacitor, 10v, L7, 20%, 10V, X5R TDK, C1005X5R1A105K050BB 12 2 D1, D2, D4 Schottky Diode, 30V Diodes Inc., SDM03U40-7 13 4 J1, J2, J3, J4 Banana Jack Keystone, 575-4 14 1 L1 Inductor, 1.0uH, 22A Cooper Bussman, HCF1305-1R0-F	
4 6 C2, C4, C7, C9, C15, C19 Capacitor, 0.1uF, 10%, 25V, X5R TDK, C1005XSR1E104K 5 2 C5, C8 Capacitor, 4.7uF, 10%, 10V, X5R TDK, C1608XSR1A475K 6 1 C10 Capacitor, 10uF, 20%, 35V, X5R Tajyo Yuden, GMK325BJ106KN 7 2 C11, C22, C23 Capacitor, 4.7uF, 10%, 10V, X5R TDK, C2012X6S1V475K125AB 8 4 C13, C14, C20, C21 Capacitor, 4.7uF, 20%, 10V, X5R TDK, C2012X6S1V475K125AB 9 2 C16, C17 Capacitor, 100µF, 5%, 50V, NP0 Kemet, C0402C101K5GACTU 10 1 C24 Capacitor, 100µF, 20%, 6.3V, X5R Kemet, C1206C107M9PACTU 11 2 C30, C31 Capacitor, 10uF, 20%, 10V, X5R TDK, C1005X5R1A105K050BB 12 2 D1, D2, D4 Schottky Diode, 30V Diodes Inc., SDM03U40-7 13 4 J1, J2, J3, J4 Banana Jack Keystone, 575-4 14 1 L1 Inductor, 1.0uH, 22A Cooper Bussman, HCF1305-1R0-F 15 2 Q1, Q2 eGaN® FET EPC, EPC2015 16 1 R3 Resistor, 45.0k, 1%, 1/8W Stackpole, RMCF0603FT45K3 17 2 R4, R10 Resistor, 10.0k, 1%, 1/10W Panasonic, ERJ-2RKF1002X 18 6 R5, R19, R20, R23, R24, R30 Resistor, 39 Ohm, 1%, 1/16W Stackpole, RMCF0402ZT0R00 10 1 R8 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0402ZT0R00 20 1 R8 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0402ZT0R00 21 1 R8 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0603FT39K2 21 1 R2	
5 2 C5, C8 Capacitor, 4.7uF, 10%, 10V, X5R TDK, C1608X5R1A475K 6 1 C10 Capacitor, 10uF, 20%, 35V, X5R Taiyo Yuden, GMK325BJ106KN 7 2 C11, C22, C23 Capacitor, 4.7uF, 10%, 35V, X7R TDK, C2012X6S1V475K125AB 8 4 C13, C14, C20, C21 Capacitor, 100PF, 5%, 50V, NPO TDK, C2012X5R1A476M 9 2 C16, C17 Capacitor, 100PF, 5%, 50V, NPO Kemet, C0402C101K5GACTU 10 1 C24 Capacitor, 100UF, 20%, 6.3V, X5R Kemet, C1206C107M9PACTU 11 2 C30, C31 Capacitor, 100UF, 20%, 10V, X5R TDK, C1005X5R1A105K050BB 12 2 D1, D2, D4 Schottky Diode, 30V Diodes Inc., SDM03U40-7 13 4 J1, J2, J3, J4 Banana Jack Keystone, 575-4 14 1 L1 Inductor, 1.0uH, 22A Cooper Bussman, HCF1305-1R0-F 15 2 Q1, Q2 eGaN* FET EPC, EPC2015 16 1 R3 Resistor, 45.0k, 1%, 1/8W Stackpole, RMCF0603FT45K3 17 2	
6 1 C10 Capacitor, 10uF, 20%, 35V, X5R Taiyo Yuden, GMK325BJ106KN 7 2 C11, C22, C23 Capacitor, 4.7uF, 10%, 35V, X7R TDK, C2012X6S1V475K125AB 8 4 C13, C14, C20, C21 Capacitor, 47uF, 20%, 10V, X5R TDK, C2012X5R1A476M 9 2 C16, C17 Capacitor, 100pF, 5%, 50V, NP0 Kemet, C0402C101K5GACTU 10 1 C24 Capacitor, 100uF, 20%, 6.3V, X5R Kemet, C1206C107M9PACTU 11 2 C30, C31 Capacitor, 1uF, 20%, 10V, X5R TDK, C1005X5R1A105K050BB 12 2 D1, D2, D4 Schottky Diode, 30V Diodes Inc., 5DM03U40-7 13 4 J1, J2, J3, J4 Banana Jack Keystone, 575-4 14 1 L1 Inductor, 1.0uH, 22A Cooper Bussman, HCF1305-1R0-F 15 2 Q1, Q2 eGAN* FET EPC, EPC2015 16 1 R3 Resistor, 45.0k, 1%, 1/8W Stackpole, RMCF0603FT45K3 17 2 R4, R10 Resistor, 39.0k, 1%, 1/10W Panasonic, ERJ-2RKF1002X 18 6	
8 4 C13, C14, C20, C21 Capacitor, 47uF, 20%, 10V, X5R TDK, C2012X5R1A476M 9 2 C16, C17 Capacitor, 100pF, 5%, 50V, NPO Kemet, C0402C101K5GACTU 10 1 C24 Capacitor, 100uF, 20%, 6.3V, X5R Kemet, C1206C107M9PACTU 11 2 C30, C31 Capacitor, 1uF, 20%, 10V, X5R TDK, C1005X5R1A105K050BB 12 2 D1, D2, D4 Schottky Diode, 30V Diodes Inc., SDM03U40-7 13 4 J1, J2, J3, J4 Banana Jack Keystone, 575-4 14 1 L1 Inductor, 1.0uH, 22A Cooper Bussman, HCF1305-1R0-F 15 2 Q1, Q2 eGAN* FET EPC, EPC2015 16 1 R3 Resistor, 45.0k, 1%, 1/8W Stackpole, RMCF0603FT45K3 17 2 R4, R10 Resistor, 10.0k, 1%, 1/10W Panasonic, ERJ-2RKF1002X 18 6 R5, R19, R20, R23, R24, R30 Resistor, 39 Ohm, 1%, 1/16W Stackpole, RMCF0402FT39R0 20 1 R8 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0603FT39K2 21 1 <td></td>	
8 4 C13, C14, C20, C21 Capacitor, 47uF, 20%, 10V, X5R TDK, C2012X5R1A476M 9 2 C16, C17 Capacitor, 100pF, 5%, 50V, NPO Kemet, C0402C101K5GACTU 10 1 C24 Capacitor, 100uF, 20%, 6.3V, X5R Kemet, C1206C107M9PACTU 11 2 C30, C31 Capacitor, 1uF, 20%, 10V, X5R TDK, C1005X5R1A105K050BB 12 2 D1, D2, D4 Schottky Diode, 30V Diodes Inc., SDM03U40-7 13 4 J1, J2, J3, J4 Banana Jack Keystone, 575-4 14 1 L1 Inductor, 1.0uH, 22A Cooper Bussman, HCF1305-1R0-F 15 2 Q1, Q2 eGaN* FET EPC, EPC2015 16 1 R3 Resistor, 45.0k, 1%, 1/8W Stackpole, RMCF0603FT45K3 17 2 R4, R10 Resistor, 10.0k, 1%, 1/10W Panasonic, ERJ-2RKF1002X 18 6 R5, R19, R20, R23, R24, R30 Resistor, 39 Ohm, 1%, 1/16W Stackpole, RMCF0402FT39R0 20 1 R8 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0603FT39K2 21 1 <td></td>	
9 2 C16, C17 Capacitor, 100pF, 5%, 50V, NPO Kemet, C0402C101K5GACTU 10 1 C24 Capacitor, 100uF, 20%, 6.3V, X5R Kemet, C1206C107M9PACTU 11 2 C30, C31 Capacitor, 1uF, 20%, 10V, X5R TDK, C1005X5R1A105K050BB 12 2 D1, D2, D4 Schottky Diode, 30V Diodes Inc., SDM03U40-7 13 4 J1, J2, J3, J4 Banana Jack Keystone, 575-4 14 1 L1 Inductor, 1.0uH, 22A Cooper Bussman, HCF1305-1R0-F 15 2 Q1, Q2 eGaN® FET EPC, EPC2015 16 1 R3 Resistor, 45.0k, 1%, 1/8W Stackpole, RMCF0603FT45K3 17 2 R4, R10 Resistor, 10.0k, 1%, 1/10W Panasonic, ERJ-2RKF1002X 18 6 R5, R19, R20, R23, R24, R30 Resistor, 0 Ohm, 1/16W Stackpole, RMCF0402ZT0R00 19 1 R31 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0603FT39K2 20 1 R8 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0603FT18K0	
11 2 C30, C31 Capacitor, 1uF, 20%, 10V, X5R TDK, C1005X5R1A105K050BB 12 2 D1, D2, D4 Schottky Diode, 30V Diodes Inc., SDM03U40-7 13 4 J1, J2, J3, J4 Banana Jack Keystone, 575-4 14 1 L1 Inductor, 1.0uH, 22A Cooper Bussman, HCF1305-1R0-F 15 2 Q1, Q2 eGaN* FET EPC, EPC2015 16 1 R3 Resistor, 45.0k, 1%, 1/8W Stackpole, RMCF0603FT45K3 17 2 R4, R10 Resistor, 10.0k, 1%, 1/10W Panasonic, ERJ-2RKF1002X 18 6 R5, R19, R20, R23, R24, R30 Resistor, 0 Ohm, 1/16W Stackpole, RMCF0402ZT0R00 19 1 R31 Resistor, 39 Ohm, 1%, 1/16W Stackpole, RMCF0402FT39R0 20 1 R8 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0603FT39K2 21 1 R2 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0603FT18K0	
11 2 C30, C31 Capacitor, 1uF, 20%, 10V, X5R TDK, C1005X5R1A105K050BB 12 2 D1, D2, D4 Schottky Diode, 30V Diodes Inc., SDM03U40-7 13 4 J1, J2, J3, J4 Banana Jack Keystone, 575-4 14 1 L1 Inductor, 1.0uH, 22A Cooper Bussman, HCF1305-1R0-F 15 2 Q1, Q2 eGaN* FET EPC, EPC2015 16 1 R3 Resistor, 45.0k, 1%, 1/8W Stackpole, RMCF0603FT45K3 17 2 R4, R10 Resistor, 10.0k, 1%, 1/10W Panasonic, ERJ-2RKF1002X 18 6 R5, R19, R20, R23, R24, R30 Resistor, 0 Ohm, 1/16W Stackpole, RMCF0402TT0R00 19 1 R31 Resistor, 39 Ohm, 1%, 1/16W Stackpole, RMCF0402FT39R0 20 1 R8 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0603FT39K2 21 1 R2 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0603FT18K0	
12 2 D1, D2, D4 Schottky Diode, 30V Diodes Inc., SDM03U40-7 13 4 J1, J2, J3, J4 Banana Jack Keystone, 575-4 14 1 L1 Inductor, 1.0uH, 22A Cooper Bussman, HCF1305-1R0-F 15 2 Q1, Q2 eGaN* FET EPC, EPC2015 16 1 R3 Resistor, 45.0k, 1%, 1/8W Stackpole, RMCF0603FT45K3 17 2 R4, R10 Resistor, 10.0k, 1%, 1/10W Panasonic, ERJ-2RKF1002X 18 6 R5, R19, R20, R23, R24, R30 Resistor, 0 Ohm, 1/16W Stackpole, RMCF0402ZT0R00 19 1 R31 Resistor, 39 Ohm, 1%, 1/16W Stackpole, RMCF0402FT39R0 20 1 R8 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0603FT39K2 21 1 R2 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0603FT18K0	
13 4 J1, J2, J3, J4 Banana Jack Keystone, 575-4 14 1 L1 Inductor, 1.0uH, 22A Cooper Bussman, HCF1305-1R0-F 15 2 Q1, Q2 eGaN® FET EPC, EPC2015 16 1 R3 Resistor, 45.0k, 1%, 1/8W Stackpole, RMCF0603FT45K3 17 2 R4, R10 Resistor, 10.0k, 1%, 1/10W Panasonic, ERJ-2RKF1002X 18 6 R5, R19, R20, R23, R24, R30 Resistor, 0 Ohm, 1/16W Stackpole, RMCF0402ZT0R00 19 1 R31 Resistor, 39 Ohm, 1%, 1/16W Stackpole, RMCF0402FT39R0 20 1 R8 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0603FT39K2 21 1 R2 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0603FT18K0	
14 1 L1 Inductor, 1.0uH, 22A Cooper Bussman, HCF1305-1R0-F 15 2 Q1, Q2 eGaN* FET EPC, EPC2015 16 1 R3 Resistor, 45.0k, 1%, 1/8W Stackpole, RMCF0603FT45K3 17 2 R4, R10 Resistor, 10.0k, 1%, 1/10W Panasonic, ERJ-2RKF1002X 18 6 R5, R19, R20, R23, R24, R30 Resistor, 0 Ohm, 1/16W Stackpole, RMCF0402ZT0R00 19 1 R31 Resistor, 39 Ohm, 1%, 1/16W Stackpole, RMCF0402FT39R0 20 1 R8 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0603FT39K2 21 1 R2 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0603FT18K0	
16 1 R3 Resistor, 45.0k, 1%, 1/8W Stackpole, RMCF0603FT45K3 17 2 R4, R10 Resistor, 10.0k, 1%, 1/10W Panasonic, ERJ-2RKF1002X 18 6 R5, R19, R20, R23, R24, R30 Resistor, 0 Ohm, 1/16W Stackpole, RMCF0402ZT0R00 19 1 R31 Resistor, 39 Ohm, 1%, 1/16W Stackpole, RMCF0402FT39R0 20 1 R8 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0603FT39K2 21 1 R2 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0603FT18K0	
16 1 R3 Resistor, 45.0k, 1%, 1/8W Stackpole, RMCF0603FT45K3 17 2 R4, R10 Resistor, 10.0k, 1%, 1/10W Panasonic, ERJ-2RKF1002X 18 6 R5, R19, R20, R23, R24, R30 Resistor, 0 Ohm, 1/16W Stackpole, RMCF0402ZT0R00 19 1 R31 Resistor, 39 Ohm, 1%, 1/16W Stackpole, RMCF0402FT39R0 20 1 R8 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0603FT39K2 21 1 R2 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0603FT18K0	
17 2 R4, R10 Resistor, 10.0k, 1%, 1/10W Panasonic, ERJ-2RKF1002X 18 6 R5, R19, R20, R23, R24, R30 Resistor, 0 Ohm, 1/16W Stackpole, RMCF0402ZT0R00 19 1 R31 Resistor, 39 Ohm, 1%, 1/16W Stackpole, RMCF0402FT39R0 20 1 R8 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0603FT39K2 21 1 R2 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0603FT18K0	
19 1 R31 Resistor, 39 Ohm, 1%, 1/16W Stackpole, RMCF0402FT39R0 20 1 R8 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0603FT39K2 21 1 R2 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0603FT18K0	
19 1 R31 Resistor, 39 Ohm, 1%, 1/16W Stackpole, RMCF0402FT39R0 20 1 R8 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0603FT39K2 21 1 R2 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0603FT18K0	
20 1 R8 Resistor, 39.2k, 1%, 1/8W Stackpole, RMCF0603FT39K2 21 1 R2 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0603FT18K0	
21 1 R2 Resistor, 18.0k, 1%, 1/8W Stackpole, RMCF0603FT18K0	
22 1 R9 Resistor, 2.2 Ohm, 5%, 1/16W Yageo, RC0402FR-072R2L	
23 1 R11 Resistor, 560K, 1%, 1/8W Stackpole, RMCF0603FT560K	
24 1 R12 Resistor, 100k, 1%, 1/8W Stackpole, RMCF0603FT100K	
25 2 R13, R14 Resistor, 1.00k, 5%, 1/10W Rohm, MCR03EZPJ102	
26 1 R15 Resistor, 3.3k, 5%, 1/8W Stackpole, RMCF0603JT3K30	
27 1 R21 Resistor, 7.5 Ohm, 5%, 1/16W Stackpole, RMCF0603JT7R50	
28 1 R22 Resistor, 47 Ohm, 5%, 1/16W Stackpole, RMCF0603JT47R0	
29 9 TP1, TP2, TP3, TP4, TP5, TP6, TP7, TP8, TP9 Measurement Point Keystone Elect, 5015	
30 1 U1 I.C., Buck Regulator Linear Technology, LTC3833EUDC	PBF
31 1 U2 I.C., Gate Driver Texas Instruments, LM5113	
32 1 U3 I.C., Logic Fairchild, NC7SZ00L6X	
33 1 U4 I.C., Charge Pump Texas Instruments, LM2766M6	
34 4 Nylon Stand-offs Keystone, 8834	
35 0 P1, P2 Optional Potentiometer, 500 Ohm, 0.25W	
36 0 R7, R16 Optional Resistors	
37 0 C6, C18 Optional Capacitors	
38 0 SJ5 Optional Scope Jack	
39 0 D3 Optional Diode	
40 0 SJ1, SJ2, SJ3, SJ4 Optional SMA connectors	



Contact us:

www.epc-co.com

Renee Yawger WW Marketing

Office: +1.908.475.5702 Mobile: +1.908.619.9678 renee.yawger@epc-co.com

Stephen Tsang Sales, Asia

Mobile: +852.9408.8351 stephen.tsang@epc-co.com

Bhasy Nair Global FAE Support

Office: +1.972.805.8585 Mobile: +1.469.879.2424 bhasy.nair@epc-co.com

Peter Cheng FAE Support, Asia

Mobile: +886.938.009.706 peter.cheng@epc-co.com





EPC Products are distributed exclusively through Digi-Key. www.digikey.com

Demonstration Board Notification

The EPC9107 board is intended for product evaluation purposes only and is not intended for commercial use. As an evaluation tool, it is not designed for compliance with the European Union directive on electromagnetic compatibility or any other such directives or regulations. As board builds are at times subject to product availability it is possible that boards may contain components or assembly materials that are not RoHS compliant. Efficient Power Conversion Corporation (EPC) makes no guarantee that the purchased board is 100% RoHS compliant. No Licenses are implied or granted under any patent right or other intellectual property whatsoever. EPC assumes no Biability for applications assistance, ususmore product design, software performance, or infringeneum of patents or any other intellectual property without 50 and kind.

EPC reserves the right at any time, without notice, to change said circuitry and specifications.